

# DFM800NXM33-A000

# **Fast Recovery Diode Module**

**Preliminary Information** 

DS5473-1.3 October 2001

### **FEATURES**

- Low Reverse Recovery Charge
- High Switching Speed
- Low Forward Voltage Drop
- Isolated Base
- Dual Diodes Can Be Paralleled for 1600A Rating
- MMC Baseplate With AIN Substrates

### **APPLICATIONS**

- Brake Chopper Diode
- Boost and Buck Converters
- Free-wheel Circuits
- Motor Drives
- Resonant Converters
- Induction Heating
- Multi-level Switch Inverters

The DFM800NXM33-A000 is a dual 3300 volt, fast recovery diode (FRD) module. Designed for low power loss, the module is suitable for a variety of high voltage applications in motor drives and power conversion.

Fast switching times and low reverse recovery losses allow high frequency operation making the device suitable for the latest drive designs employing pwm and high frequency switching.

These modules incorporate electrically isolated base plates and low inductance construction enabling circuit designers to optimise circuit layouts and utilise grounded heat sinks for safety.

#### ORDERING INFORMATION

Order As:

#### DFM800NXM33-A000

Note: When ordering, please use the complete part number.



$V_{RRM}$		3300V
V <sub>F</sub>	(typ)	2.5V
I,	(max)	800A
I <sub>EM</sub>	(max)	1600A

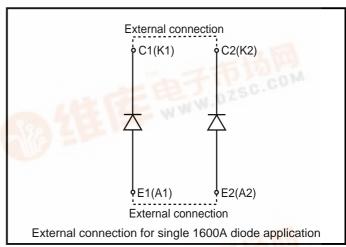


Fig. 1 Circuit diagram

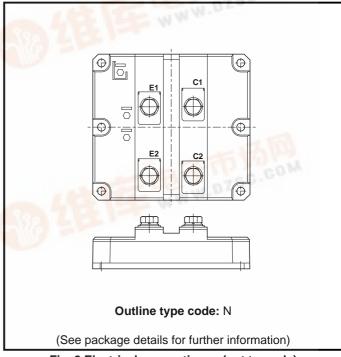


Fig. 2 Electrical connections - (not to scale)





### **ABSOLUTE MAXIMUM RATINGS - PER ARM**

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

T<sub>case</sub> = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
$V_{RRM}$	Repetitive peak reverse voltage	T <sub>vj</sub> = 125°C	3300	V
l <sub>F</sub>	Forward current (per arm)	DC, T <sub>case</sub> = 70°C	800	А
I <sub>FM</sub>	Max. forward current	$T_{case} = 115$ °C, $t_p = 1$ ms	1600	Α
l²t	I²t value fuse current rating	$V_R = 0, t_p = 10 \text{ms}, T_{v_j} = 125^{\circ}\text{C}$	320	A²s
Pmax	Maximum power dissipation	T <sub>case</sub> = 25°C, T <sub>vj</sub> = 125°C	3845	W
$V_{isol}$	Isolation voltage	Commoned terminals to base plate. AC RMS, 1 min, 50Hz	6	kV
$Q_{pd}$	Partial discharge	IEC1287. V <sub>1</sub> = 2450V, V <sub>2</sub> = 1800V, 50Hz RMS	10	рС

## THERMAL AND MECHANICAL RATINGS

Internal insulation: AIN
Baseplate material: AISiC
Creepage distance: 33mm
Clearance: 20mm
CTI (Critical Tracking Index): 175

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance - diode (per arm)	Continuous dissipation -	-	-	26	°C/kW
		junction to case				
R <sub>th(c-h)</sub>	Thermal resistance - case to heatsink	Mounting torque 5Nm	-	-	6	°C/kW
	(per module)	(with mounting grease)				
T <sub>j</sub>	Junction temperature	-	-40	-	125	°C
T <sub>stg</sub>	Storage temperature range	-	-	-	125	°C
-	Screw torque	Mounting - M6	-	-	5	Nm
		Electrical connections - M8	-	-	10	Nm



# STATIC ELECTRICAL CHARACTERISTICS - PER ARM

# $T_{vj}$ = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
I <sub>RM</sub>	Peak reverse current	V <sub>R</sub> = 3300V, T <sub>vj</sub> = 125°C	-	-	60	mA
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 800A	-	2.5	-	V
		I <sub>F</sub> = 800A, T <sub>vj</sub> = 125°C	-	2.5	-	V
L	Inductance	-	-	25	-	nH

# **DYNAMIC ELECTRICAL CHARACTERISTICS - PER ARM**

# $T_{vi}$ = 25°C unless stated otherwise.

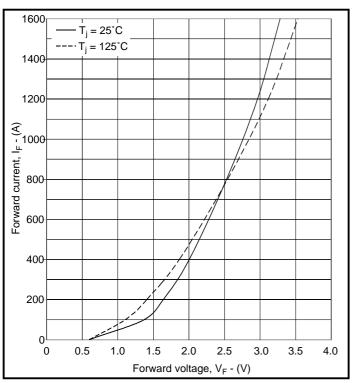
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
I <sub>rr</sub>	Peak reverse recovery current	I <sub>F</sub> = 800A,	-	650	-	Α
Q <sub>rr</sub>	Reverse recovery charge	dI <sub>F</sub> /dt = 4400A/μs,	-	450	-	μС
E <sub>rec</sub>	Reverse recovery energy	V <sub>R</sub> = 1800V	-	500	-	mJ

# $T_{vj}$ = 125°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
I <sub>m</sub>	Peak reverse recovery current	I <sub>F</sub> = 800A,	-	670	-	А
Q <sub>rr</sub>	Reverse recovery charge	$dI_{F}/dt = 3000A/\mu s,$	-	670	-	μС
E <sub>rec</sub>	Reverse recovery energy	V <sub>R</sub> = 1800V	-	850	-	mJ

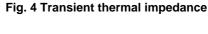


### TYPICAL CHARACTERISTICS



100 Diode P<sub>i</sub> (°C/KW) 0.7386 3.9115 5.5628 16.8308 T<sub>i</sub> (ms) 0.0843 3.7205 33.2138 236.5275 0.001 0.01 0.1 1 10 Pulse width, t<sub>p</sub> - (s)

Fig. 2 Diode typical forward characteristics



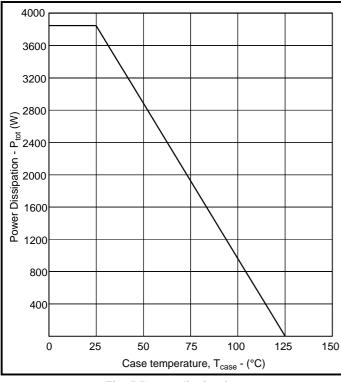


Fig. 5 Power dissipation

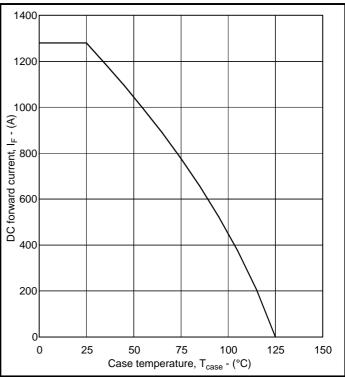


Fig. 6DC current rating vs case temperature



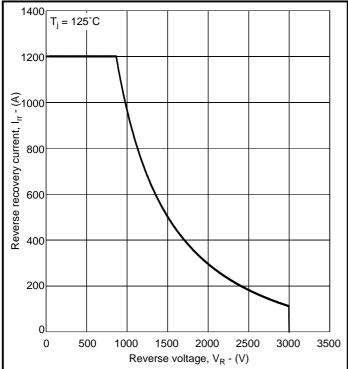
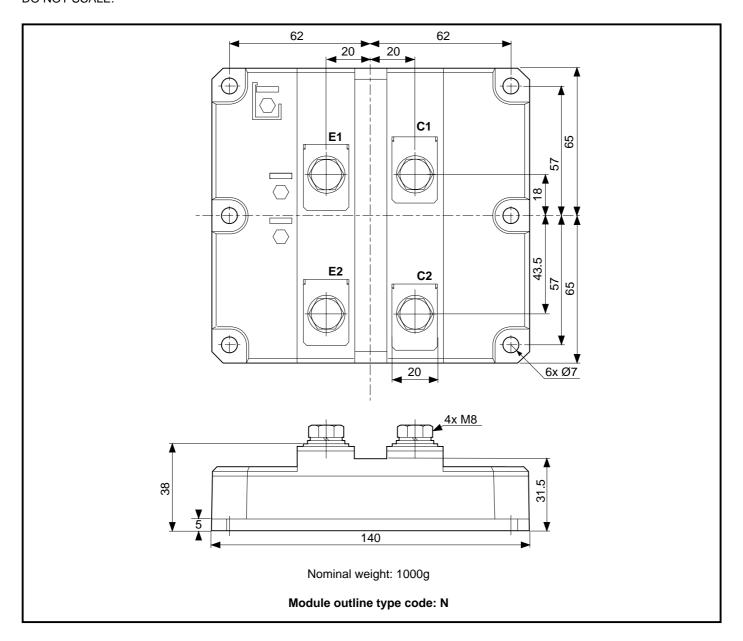


Fig. 7 RBSOA



# **PACKAGE DETAILS**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





#### POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

#### **HEATSINKS**

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or customer service office.



#### http://www.dynexsemi.com

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Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

Advance Information: The product design is complete and final characterisation for volume production is well in hand.

No Annotation: The product parameters are fixed and the product is available to datasheet specification.

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